

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









## 0.8 A sensitive gate SCR

#### Datasheet - production data

#### **Features**

- $I_{T(RMS)} = 0.8 A$
- V<sub>DRM</sub>, V<sub>RRM</sub> = 600 V
- $I_{GT} = 30 \text{ to } 200 \mu A$

### **Applications**

- Limited gate current topologies
- Ground fault circuit interrupters
- Overvoltage crowbar protection in power supplies
- Protection in electronic ballasts
- Capacitive discharge ignitions
- Ignitors (lighting, oven...)

### **Description**

The X006 SCR can be used as on/off function in applications where topology does not offer high current for gate triggering.

This device is optimized in forward voltage drop and inrush current capabilities for reduced power losses and high reliability in harsh environments.

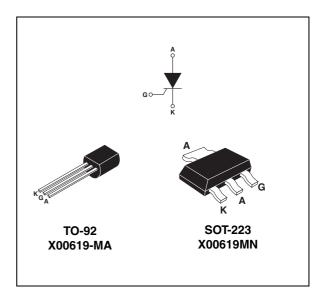


Table 1. Device summary

I <sub>T(RMS)</sub>	0.8 A
$V_{DRM} / V_{RRM}$	600 V
I <sub>GT</sub>	30 to 200 μA

Characteristics X00619

## 1 Characteristics

Table 2. Absolute ratings (limiting values,  $T_j = 25$  °C unless otherwise specified)

Symbol	Parameter	Value	Unit		
1	On-state rms current (180 °Conduction angle)	TO-92	T <sub>L</sub> = 83 °C	- 0.8	А
I <sub>T(RMS)</sub>	Off-state fins current (180° Conduction angle)	SOT-223	T <sub>c</sub> = 107 °C		
IT.	Average on-state current (180 °Conduction angle)	TO-92	T <sub>L</sub> = 83 °C	0.5	А
IT <sub>(AV)</sub>	Average on-state current (100 Conduction angle)	SOT-223	T <sub>c</sub> = 107 °C	0.5	
	Non repetitive surge peak on-state current	$t_p = 8.3 \text{ ms}$	T <sub>i</sub> = 25 °C	10	Α
ITSM		t <sub>p</sub> = 10 ms	1 j = 25 C	9	
l <sup>2</sup> t	$I^2t$ Value for fusing $t_p =$		T <sub>j</sub> = 25 °C	0.4	A <sup>2</sup> s
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$ $F = 60 \text{ Hz}$		T <sub>j</sub> = 125 °C	50	A/µs
I <sub>GM</sub>	Peak gate current $t_p = 20 \ \mu s \qquad T_j = 125 \ ^{\circ}C$		T <sub>j</sub> = 125 °C	1	Α
P <sub>G(AV)</sub>	Average gate power dissipation	0.1	W		
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range				°C

Table 3. Electrical characteristics ( $T_j = 25$  °C unless otherwise specified)

Symbol	Test conditions	Value	Unit			
1.			MIN.	30	^	
'GT	$I_{GT}$ $V_D = 12 \text{ V}, R_L = 140 \Omega$		MAX.	200	μΑ	
V <sub>GT</sub>			IVIAA.	0.8	V	
V <sub>GD</sub>	$V_D = V_{DRM,} R_L = 3.3 \text{ k}\Omega, R_{GK} = 1 \text{ k}\Omega$ $T_j = 125 \text{ °C}$		MIN.	0.2	V	
V <sub>RG</sub>	I <sub>RG</sub> = 10 μA			5	V	
I <sub>H</sub>	$I_T = 50 \text{ mA}, R_{GK} = 1 \text{ k}\Omega$			5	mA	
IL	$I_{G}$ = 1 mA, $R_{GK}$ = 1 k $\Omega$		MAX.	6	mA	
dV/dt	$V_D = 67\% V_{DRM,} R_{GK} = 1 k\Omega$ $T_j = 125 °C$		MIN.	40	V/µs	

Table 4. Static electrical characteristics

Symbol	Test conditions			Value	Unit
V <sub>TM</sub>	$I_{TM} = 1 \text{ A, } t_p = 380  \mu\text{s}$	T <sub>j</sub> = 25 °C		1.35	V
V <sub>TO</sub>	Threshold voltage	T <sub>i</sub> = 125 °C		0.85	V
R <sub>d</sub>	Dynamic resistance	1 <sub>j</sub> = 125 C	MAX	245	mΩ
I <sub>DRM</sub> I <sub>RRM</sub>	$V_{DRM} = V_{RRM}, R_{GK} = 1 \text{ k}\Omega$	T <sub>j</sub> = 25 °C		1	μΑ
		T <sub>j</sub> = 125 °C		100	μΑ

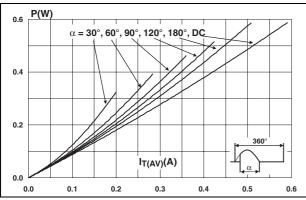
X00619 Characteristics

Table 5. Thermal resistances

Symbol	Parameter				Value	Unit
R <sub>th(j-l)</sub>	Junction to leads (DC)		TO-92		70	
R <sub>th(j-c)</sub>	Junction to case (DC)		SOT-223	Max.	30	°C/W
D. Lunation to ambient (DC)			TO-92	iviax.	150	C/VV
R <sub>th(j-a)</sub>	Junction to ambient (DC)	$S = 5 \text{ cm}^2$	SOT-223		60	

Figure 1. Maximum average power dissipation versus average on-state current

Figure 2. Average and DC on-state current versus case temperature (SOT-223)



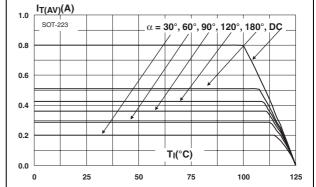
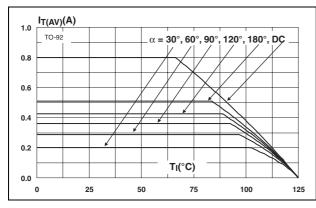
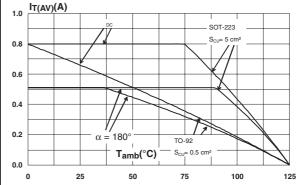


Figure 3. Average and DC on-state current versus lead temperature (TO-92)

Figure 4. Average and DC on-state current versus ambient temperature (free air convection)





Characteristics X00619

Figure 5. Relative variation of thermal impedance junction to ambient versus pulse duration

1.00 Zth(j-a)/Rth(j-a)

0.10 Sor-223 Sor-223 Sor-5 cm<sup>2</sup>

1.0E-02 1.0E-01 1.0E+00 1.0E+01 1.0E+02 1.0E+03

Figure 6. Relative variation of gate trigger, holding and latching current versus junction temperature

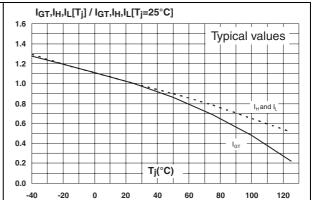


Figure 7. Relative variation of holding current versus gate-cathode resistance (typical values)

resistance (typical values)

IH[R<sub>GK</sub>] / IH[R<sub>GK</sub>=1kΩ]

3.5

2.5

2.0

1.5

R<sub>GK</sub>(kΩ)

Figure 8. Relative variation of dV/dt immunity versus gate-cathode resistance (typical values)

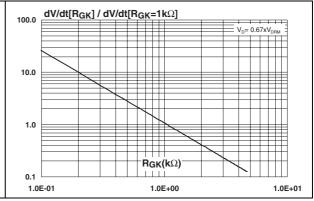
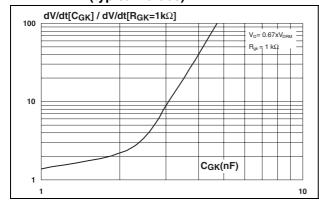
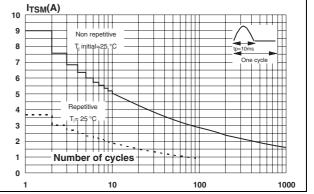


Figure 9. Relative variation of dV/dt immunity Figure 10. Surge peak on-state current versus versus gate-cathode capacitance number of cycles (typical values)





X00619 **Characteristics** 

Figure 11. current for a sinusoidal pulse and corresponding value of I<sup>2</sup>T

Non repetitive surge peak on state Figure 12. On-state characteristics (maximum values)

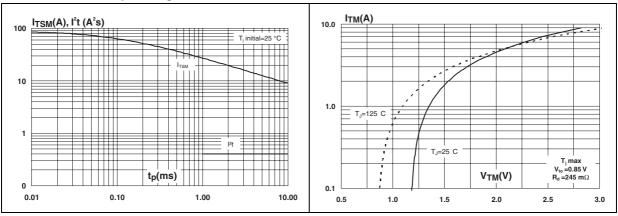
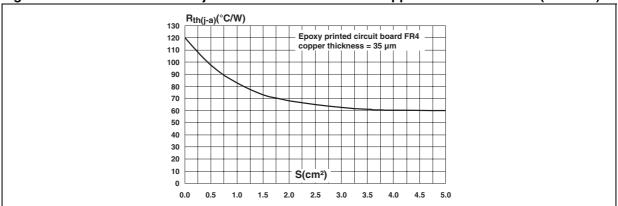
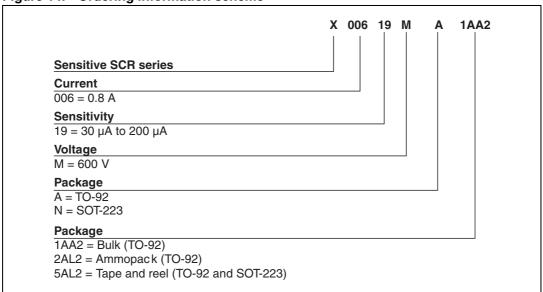


Figure 13. Thermal resistance junction to ambient versus copper surface under tab (SOT-223)



# 2 Ordering information scheme

Figure 14. Ordering information scheme



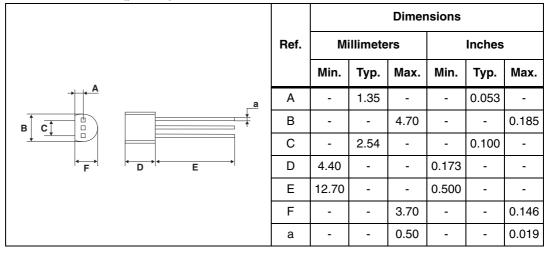
X00619 Package information

## 3 Package information

- Epoxy meets UL94, V0
- Lead-free packages

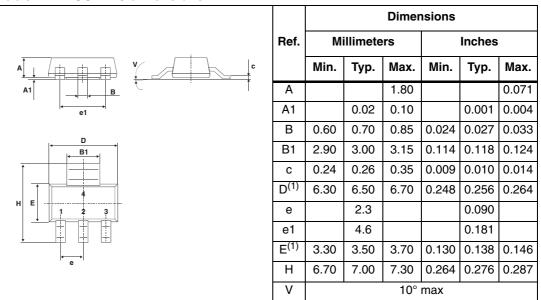
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 6. TO-92 (plastic) dimensions



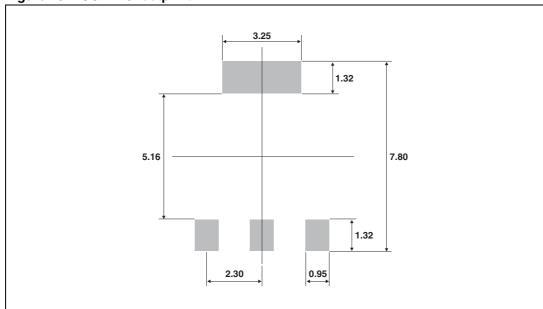
Package information X00619

Table 7. SOT-223 dimensions



<sup>1.</sup> Do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm (0.006inches)

Figure 15. SOT-223 footprint



# 4 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
X00619MA1AA2				2500	Bulk
X00619MA2AL2	X0619 MA	TO-92	0.2 g	2000	Ammopack
X00619MA5AL2				2000	Tape and reel
X00619MN5AL2	X0 619 MN	SOT-223	0.12 g	1000	rape and reel

# 5 Revision history

Table 9. Document revision history

Date	Revision	Changes
26-May-2009	1	First issue
03-May-2012	2	Added SOT-223 package.

#### Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY TWO AUTHORIZED ST REPRESENTATIVES. ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2012 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

10/10 Doc ID 15755 Rev 2

